

Silicon Carbide (SiC) Schottky Diode – EliteSiC, 8 A, 650 V, D2, TO-220-2L

FFSP0865B

Silicon Carbide (SiC) Schottky Diodes use a completely new technology that provides superior switching performance and higher reliability compared to Silicon. No reverse recovery current, temperature independent switching characteristics, and excellent thermal performance sets Silicon Carbide as the next generation of power semiconductor. System benefits include highest efficiency, faster operating frequency, increased power density, reduced EMI, and reduced system size and cost.

Features

- Max Junction Temperature 175°C
- Avalanche Rated 33 mJ
- High Surge Current Capacity
- Positive Temperature Coefficient
- Ease of Paralleling
- No Reverse Recovery / No Forward Recovery
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

Applications

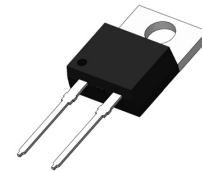
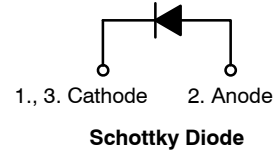
- General Purpose
- SMPS, Solar Inverter, UPS
- Power Switching Circuits

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)s

Parameter	Symbol	Value	Unit	
Peak Repetitive Reverse Voltage	V _{RRM}	650	V	
Single Pulse Avalanche Energy (T _J = 25°C, I _{L(pk)} = 11.5 A, L = 0.5 mH, V = 50 V)	E _{AS}	33	mJ	
Continuous Rectified Forward Current	@ T _C < 147	I _F	8.0	A
	@ T _C < 135		10.1	
Non-Replicative Peak Forward Surge Current	T _C = 25°C t _p = 10 μs	I _{FM}	551	A
	T _C = 150°C t _p = 10 μs		498	
Non-Replicative Forward Surge Current (Half-Sine Pulse)	T _C = 25°C t _p = 8.3 ms	I _{FSM}	56	A
Power Dissipation	T _C = 25°C	P _{tot}	73	W
	T _C = 150°C		12	
Operating Junction and Storage Temperature Range	T _J , T _{stg}	-55 to +175	°C	

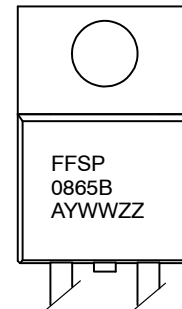
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

V _{RRM}	I _F
650 V	8.0 A



TO-220-2LD
CASE 340BB

MARKING DIAGRAM



FFSP0865B = Specific Device Code
A = Assembly Location
Y = Year
WW = Work Week
ZZ = Assembly Lot Code

ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

FFSP0865B

THERMAL CHARACTERISTICS

Parameter	Symbol	Value	Unit
Thermal Resistance, Junction-to-Case, Max.	$R_{\theta JC}$	2.05	$^{\circ}\text{C/W}$

ELECTRICAL CHARACTERISTICS ($T_J = 25^{\circ}\text{C}$ unless otherwise noted)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
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ON CHARACTERISTICS

Forward Voltage	V_F	$I_F = 8.0\text{ A}, T_J = 25^{\circ}\text{C}$		1.39	1.7	V
		$I_F = 8.0\text{ A}, T_J = 125^{\circ}\text{C}$		1.55	2.0	
		$I_F = 8.0\text{ A}, T_J = 175^{\circ}\text{C}$		1.71	2.4	
Reverse Current	I_R	$V_R = 650\text{ V}, T_J = 25^{\circ}\text{C}$		0.073	40	μA
		$V_R = 650\text{ V}, T_J = 125^{\circ}\text{C}$		0.24	80	
		$V_R = 650\text{ V}, T_J = 175^{\circ}\text{C}$		0.48	160	

CHARGES, CAPACITANCES & GATE RESISTANCE

Total Capacitive Charge	Q_C	$V_C = 400\text{ V}$		22		nC
	C_{tot}	$V_R = 1\text{ V}, f = 100\text{ kHz}$		336		pF
		$V_R = 200\text{ V}, f = 100\text{ kHz}$		39		
		$V_R = 400\text{ V}, f = 100\text{ kHz}$		30		

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

PACKAGE MARKING AND ORDERING INFORMATION

Part Number	Top Marking	Package	Packing Method	Reel Size	Tape Width	Quantity
FFSP0865B	FFSP0865B	TO-220-2L	Tube	N/A	N/A	50 Units

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, [BRD8011/D](#).

TYPICAL CHARACTERISTICS

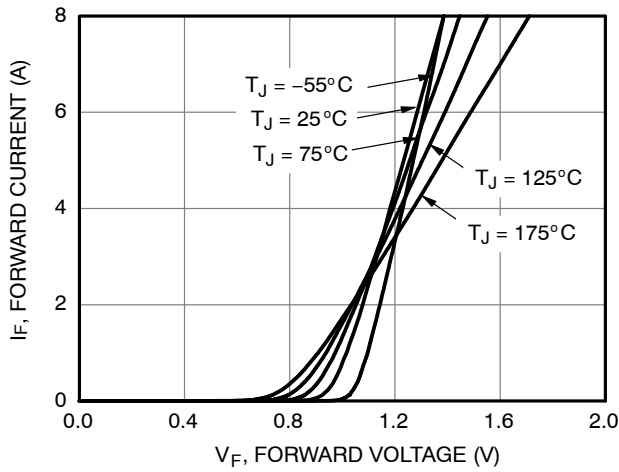


Figure 1. Forward Characteristics

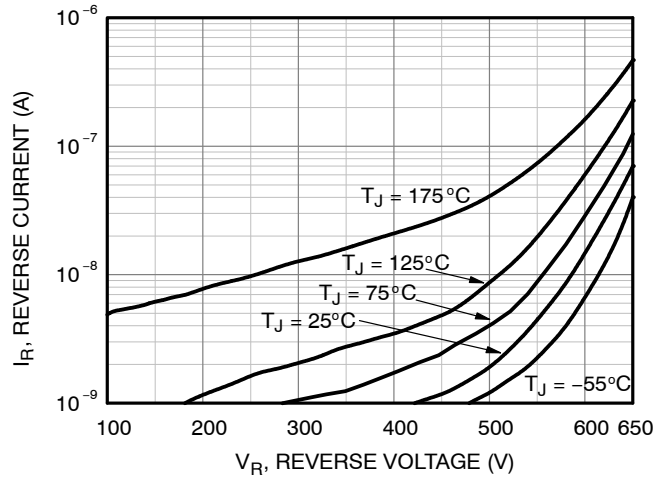


Figure 2. Reverse Characteristics

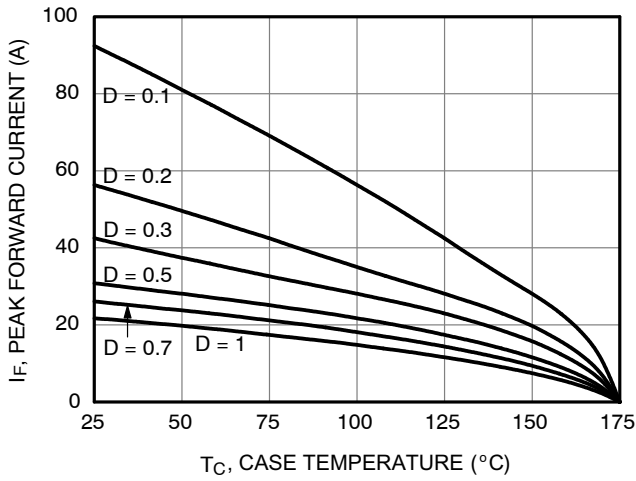


Figure 3. Current Derating

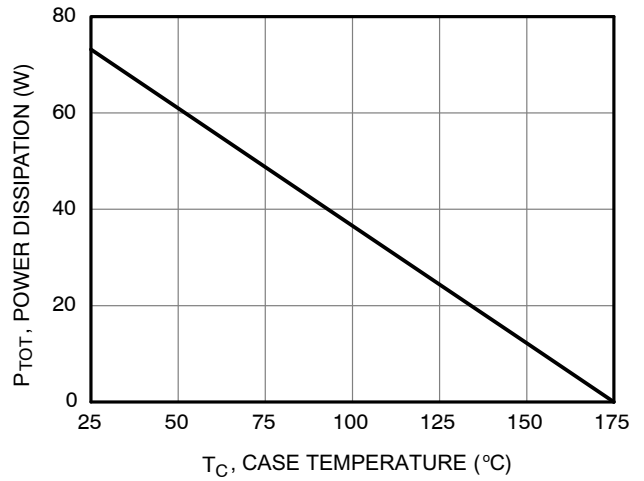


Figure 4. Power Derating

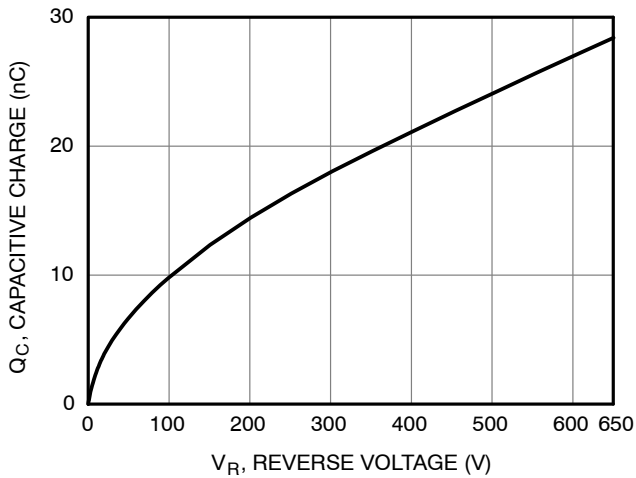


Figure 5. Capacitive Charge vs. Reverse Voltage

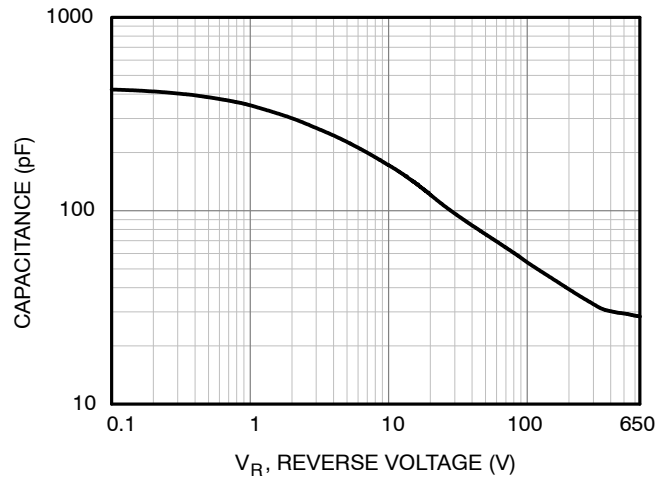


Figure 6. Capacitance vs. Reverse Voltage

TYPICAL CHARACTERISTICS

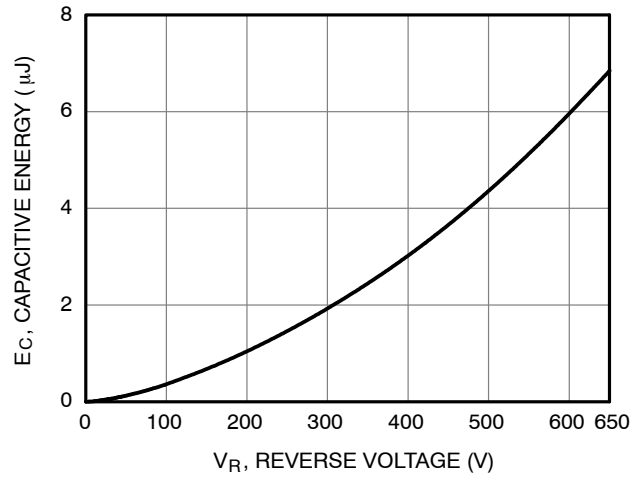


Figure 7. Capacitance Stored Energy

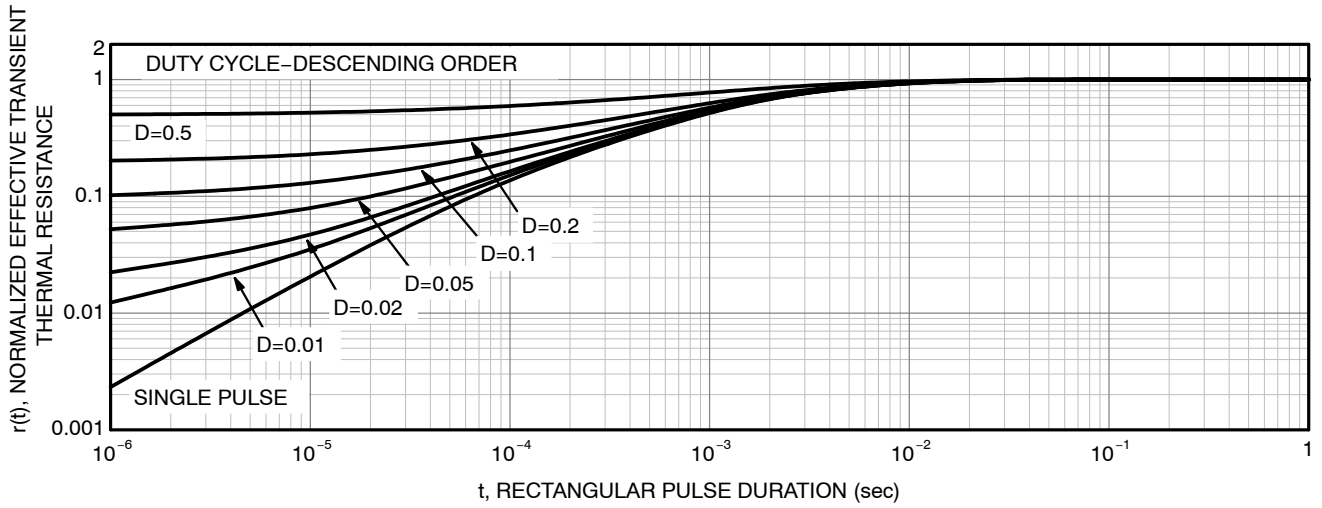


Figure 8. Junction-to-Case Transient Thermal Response

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